KJ045N10G

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☑ Advanced trench cell design
- ☑ Low thermal impedance
- ☑ Low gate charge

1.2 Applications

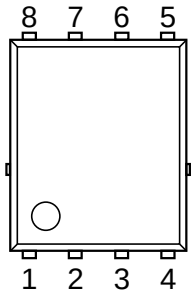
- ☑ DC/DC converter
- ☑ Power switch
- ☑ Motor drivers

1.3 Quick reference

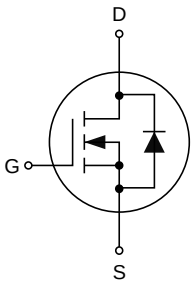
- ☑ BV ≥ 100 V
- ☑ $R_{DS(ON)}$ ≤ 4.5 mΩ @V_{GS} = 10 V
- ☑ P_D ≤ 104 W
- ☑ I_D ≤ 100 A

2. Pin Description

Pin	Description
1,2,3	Source
4	Gate
5,6,7,8	Drain



Top View
PDFN5x6-8L



3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	T_C=25℃	100	-	V
V_{GS}	Gate-Source Voltage	T_C=25℃	-	±20	V
I_D *	Continuous Drain Current	T_C=25℃, V_{GS}=10 V	-	100	A
		T_C=100℃, V_{GS}=10 V	-	79	A
I_{DM} ***	Pulsed Drain Current	T_C=25℃, V_{GS}=10 V	-	400	A
P_D	Drain Power Dissipation	T_C=25℃	-	104	W
E_{AS}	Single Pulsed Avalanche Energy	V_{DD}=50 V, L=0.5 mH	-	430	mJ
T_J, T_{stg}	Operating Junction and Storage Temperature Range		-55	150	℃
$R_{\theta JA}$ **	Thermal Resistance-Junction to Ambient		-	58	℃/W
$R_{\theta JC}$ **	Thermal Resistance-Junction to Case		-	1.2	

Notes:

* Pulse width ≤ 300 μs, duty cycle ≤ 2%.

** Surface mounted on 1 in^2 pad area, t ≤ 10 sec.

*** Pulse width limited by maximum junction temperature.

4. Marking Information

Product Name	Marking
KJ045N10G	**KJ045N10G YWWXXX** **YWWXXX: Date Code**

Ordering Code

Product Name	Package	Reel size	Tape width	Quantity (pcs)
KJ045N10G	**PDFN 5x6-8L**	**13"**	**12 mm**	**5000**

Note: KUAIJIEXIN defines “Green” as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C).

6. Electrical Characteristics (T_J=25℃ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0 V, I_{DS}=250 μA	100	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}=V_{GS}, I_{DS}=250 μA	2.4	-	3.6	V
I_{DSS}	Drain Leakage Current	V_{DS}=100 V, V_{GS}=0 V	-	-	1	μA
I_{GSS}	Gate Leakage Current	V_{DS}=0 V, V_{GS}=±20 V	-	-	±100	nA
$R_{DS(ON)}$ [a]	On-State Resistance	V_{GS}=10 V, I_{DS}=30 A	-	3.8	4.5	mΩ
g_{FS} [b]	Forward Transconductance	V_{GS}=5 V, I_{DS}=30 A	-	125	-	S
R_g	Gate Resistance	f=1 MHz	-	2.5	-	Ω
Diode Characteristics						
V_{SD} [a]	Diode Forward Voltage	V_{GS}=0 V, I_{SD}=30 A	-	0.9	1.2	V
t_{rr}	Reverse Recovery Time	V_{DS}=50 V, I_{DS}=30 A, V_{GS}=0 V, dI_{SD}/dt=100 A/μs	-	50	-	ns
Q_{rr}	Reverse Recovery Charge		-	108	-	nC
Dynamic Characteristics [b]						
C_{iss}	Input Capacitance	V_{DS}=50 V, V_{GS}=10 V, Frequency=1 MHz	-	4874	-	pF
C_{oss}	Output Capacitance		-	665	-	
C_{rss}	Reverse Transfer Capacitance		-	144	-	
$t_{d(on)}$	Turn-on Delay Time	V_{DS}=50 V, V_{GEN}=10 V, R_G=6 Ω, I_{DS}=30 A	-	63	-	ns
t_r	Turn-on Rise Time		-	70	-	
$t_{d(off)}$	Turn-off Delay Time		-	86	-	
t_f	Turn-off Fall Time		-	41	-	
Gate Charge Characteristics [b]						
Q_g	Total Gate Charge	V_{DS}=50 V, V_{GS}=10 V, I_{DS}=30 A	-	80	-	nC
Q_{gs}	Gate-Source Charge		-	22	-	
Q_{gd}	Gate-Drain Charge		-	25	-	

Notes:

a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.

b. Guaranteed by design, not subject to production testing.

7. Typical Characteristics

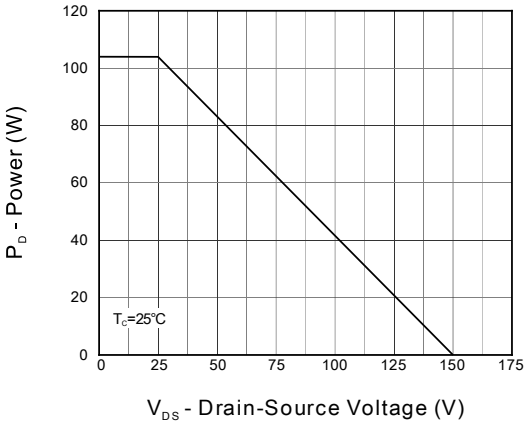


Figure 1. Output Characteristics

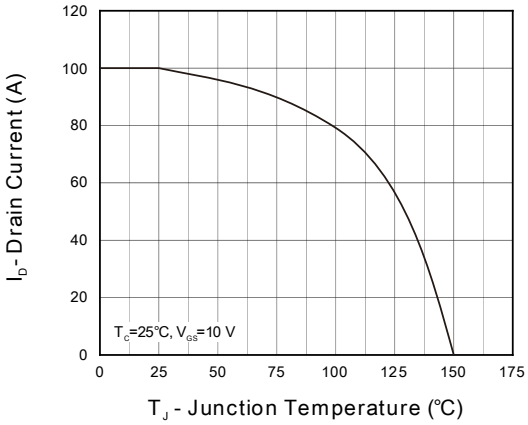


Figure 2. Current Capability

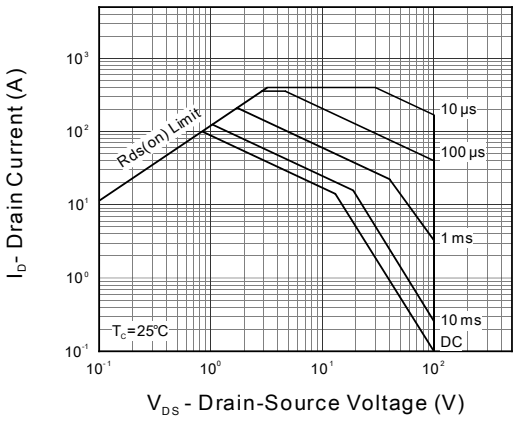


Figure 3. Safe Operation Area

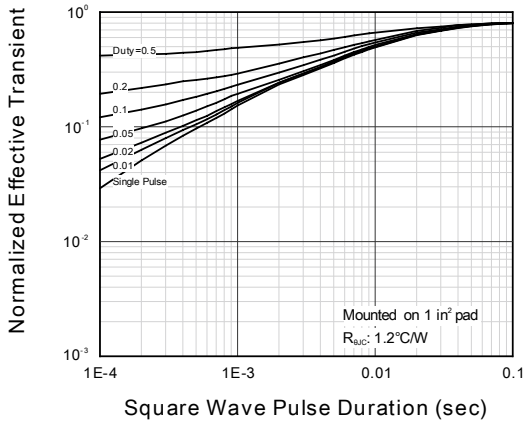


Figure 4. Transient Thermal Impedance

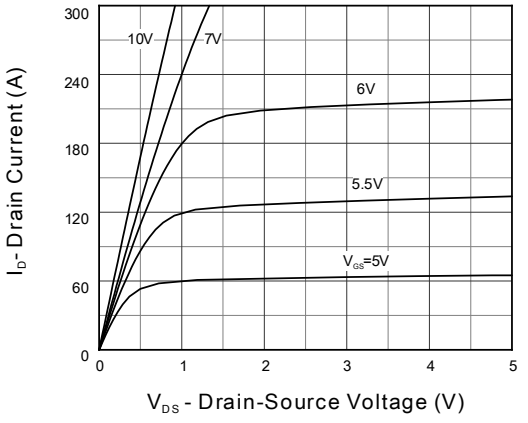


Figure 5. Output Characteristics

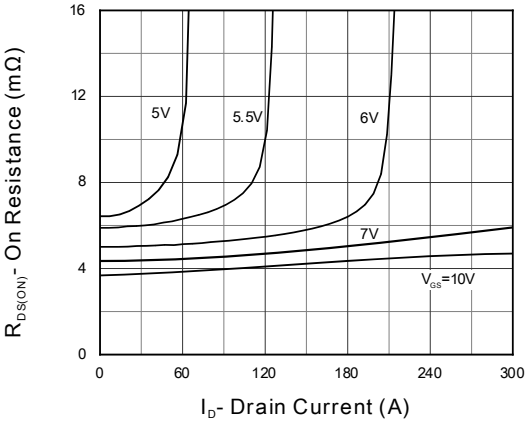


Figure 6. On Resistance

7. Typical Characteristics (cont.)

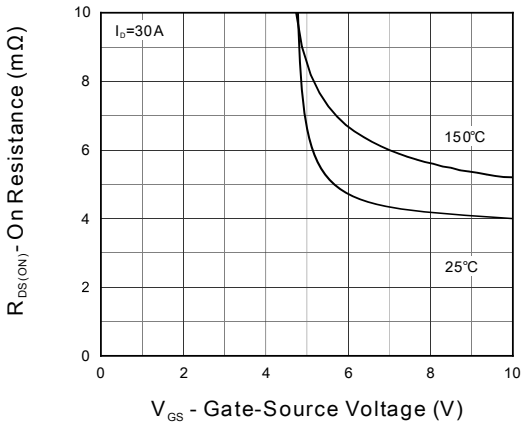


Figure 7. Transfer Characteristics

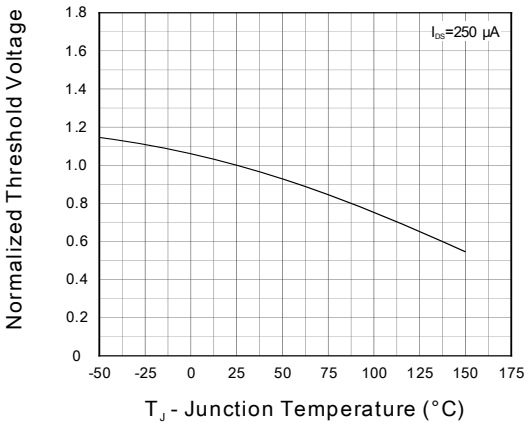


Figure 8. Normalized Threshold Voltage

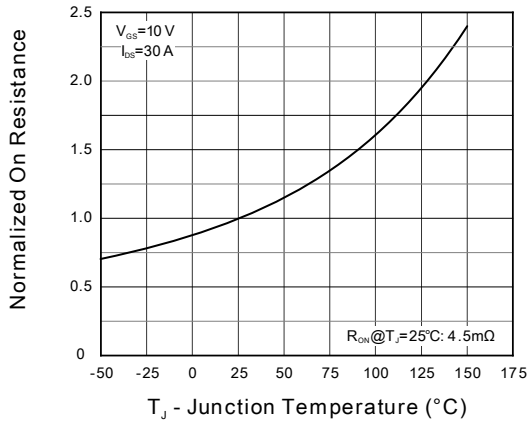


Figure 9. Normalized On Resistance

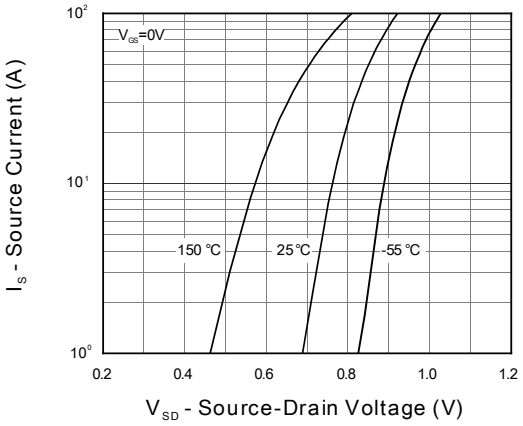


Figure 10. Diode Forward Current

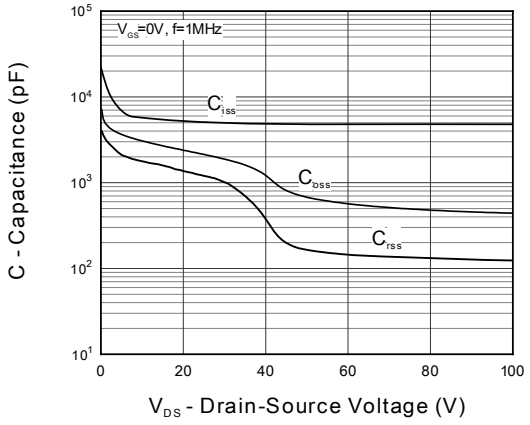


Figure 11. Capacitance

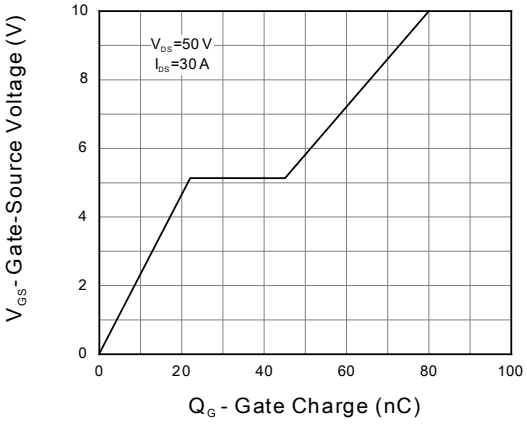
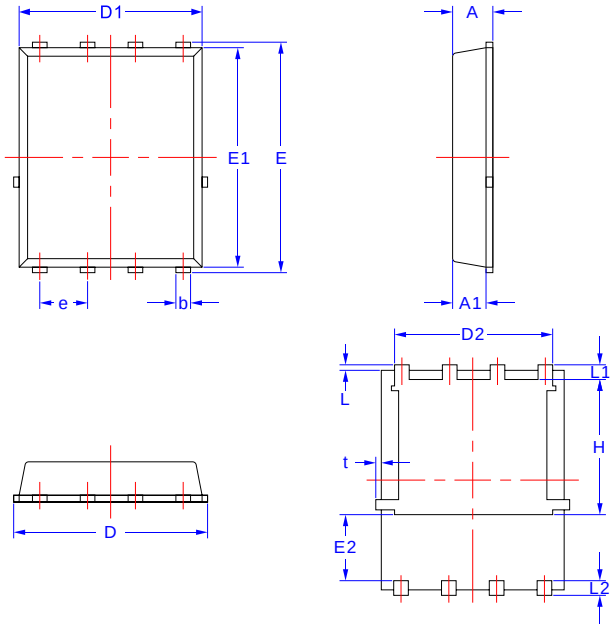


Figure 12. Gate Charge

8. Package Dimensions

PDFN 5x6-8L Package



Symbol	Dimensions in Millimeters	
	Min.	Max.
A	1.03	1.17
A1	0.82	0.97
b	0.34	0.48
D	4.80	5.40
D1	4.80	5.00
D2	4.11	4.31
E	5.95	6.15
E1	5.65	5.85
E2	1.60	-
e	1.270 BSC	
L	0.05	0.25
L1	0.38	0.50
L2	0.38	0.50
H	3.30	3.50
t	-	0.18